## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Wen Lin, et al.

Serial No.: 10/814,682

Filed: March 31, 2004

Title: SEMICONDUCTOR DEVICE HAVING A DOPED LATTICE

MATCHING LAYER AND A METHOD OF MANUFACTURE

THEREFOR

Grp./A.U.: 2823

Examiner: Julio J. Maldonado

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450 I hereby certify that this correspondence is being facsimile transmitted to the United States Patent and trademark Office Fax No. (571) 273-8300 on: June 8, 2006(Date)

Elizabeth Schumache

(Printed or typed name of person signing the certificate)

/Elizabeth Schumacher/

(Signature of the person signing the certificate)

Sir:

## **AMENDMENT UNDER 37 C.F.R. § 1.111**

In response to the Examiner's Action mailed March 21, 2006, please amend the above-identified application as follows: